



GENERAL INSTRUCTIONS TO THE CANDIDATES

1. Candidates are instructed to answer the questions as per Bloom's Taxonomy knowledge level (K<sub>1</sub> to K<sub>6</sub>)
2. Candidates are strictly instructed not to write anything in the question paper other than their roll number.
3. Candidates should search their pockets, desks and benches and handover to the Hall Superintendent/ Invigilator if any paper, book or note which they may find therein as soon as they enter the examination hall.
4. Candidates are not permitted to bring electronic watches with memory, laptop computers, personal systems, walkie-talkie sets, paging devices, mobile phones, cameras, recording systems or any other gadget / device /object that would be of unfair assistance to him / her.
5. Corrective measures as per KCT examination policies will be imposed for malpractice in the hall like copying from any papers, books or notes and attempting to elicit the answer from neighbours.

**B.E DEGREE EXAMINATIONS: JUNE 2015**

(Regulation 2014)

Second Semester

**CIVIL ENGINEERING**

U14PHT201 : Materials Science

**Time: Three Hours**

**Maximum Marks: 100**

**Answer all the Questions:-**

**PART A (10 x 1 = 10 Marks)**

1. **Assertion (A):** The free electrons move randomly in all directions, without any loss in the energy. [K<sub>1</sub>]  
**Reason (R):** The free electrons collide with each other and also with the lattice elastically.
  - a) A is false and R is True
  - b) A is True but R is false
  - c) Both A and R are True and R is the correct explanation of A.
  - d) Both A and R are True and R is not the correct explanation of A.
2. High Temperature Superconductors ( HTC) [K<sub>1</sub>]
  1. have high transition temperature



c) 4-1-3-2

d) 4-2-1-3

6. Match list I with list II and select the correct answer using the codes given below.

[K<sub>1</sub>]

List I		List II		
A. Conductance		1. $\text{m}^2 \text{V}^{-1} \text{s}^{-1}$		
B. Mobility		2. $\Omega - \text{m}$		
C. Resistivity		3. mho		
D. Lorentz Number		4. $\text{W}\Omega\text{K}^{-1}$		
	A	B	C	D
a)	2	1	4	3
b)	4	3	2	1
c)	3	1	2	4
d)	3	2	1	4

7. **Assertion ( A ) :** The materials which are easy to magnetize and demagnetize are called as soft magnetic materials.

[K<sub>1</sub>]

**Reason ( R ) :** In the soft magnetic materials, the domain wall motion will be easy.

a) Both A and R are false

b) A is true and R is false

c) Both A and R are True and R is not the correct explanation of A.

d) Both A and R are True and R is the correct explanation of A.

8. Dielectric Constant

[K<sub>1</sub>]

1. Of any dielectric material can be measured by comparing the capacity of the empty condenser ( C<sub>o</sub> ) and the condenser filled with the specimen ( C<sub>s</sub> )

2. For Diamond is 5.68

3. For Water at 0° C is 8

For Germanium is 1

a) 1 and 2 are correct

b) 2 and 3 are correct

c) 3 and 4 are correct

d) 1 and 4 are correct

9. Molten alloy is made to impinge on a fast rotating roller to form

[K<sub>1</sub>]

a) One-way shape memory alloy

b) Two-way shape memory alloy

c) Metallic glasses

d) Quantum wire

10. Ball milling technique is an example of

[K<sub>1</sub>]

a) Top Down Process

b) Bottom up Process

c) Vapour phase deposition process

d) Plasma assisted deposition process

**PART B (10 x 2 = 20 Marks)**

**(Answer not more than 40 words)**

11. Distinguish between Loudness and Intensity [K<sub>4</sub>]
12. List the conditions of good acoustics for an auditorium [K<sub>1</sub>]
13. A wire of diameter 0.16 cm carries a steady current of 10 A. Calculate the drift velocity of electrons in copper and current density. Given that  $n = 8.46 \times 10^{28}$  per m<sup>3</sup> [K<sub>4</sub>]
14. Illustrate the Meissner's effect with a diagram [K<sub>3</sub>]
15. Compare elemental and compound semiconductor [K<sub>5</sub>]
16. Define Hall Voltage [K<sub>1</sub>]
17. Explain the magneto – optical recording method [K<sub>2</sub>]
18. Distinguish Lorentz force and Coulomb force in Dielectrics [K<sub>4</sub>]
19. List the different phases of Shape memory alloys (SMA). [K<sub>1</sub>]
20. Name a few bottom up approaches for synthesizing nano materials [K<sub>1</sub>]

**Answer any FIVE Questions:-**

**PART C (5 x 14 = 70 Marks)**

**(Answer not more than 300 words)**

**Q.No. 21 is Compulsory**

21. Deduce an expression for density of holes in an intrinsic semiconductor. Describe a method for evaluating the energy gap of a semiconductor. (10+4) [K<sub>4</sub>]
22. Deduce Sabine's formula for reverberation time. [K<sub>4</sub>]
23. Explain the following. (10+4) [K<sub>2</sub>]
  - a) High Temperature Superconductors
  - b) Magnetic Levitation
24. Discuss in detail the different types of polarization mechanisms in dielectrics. Sketch their dependence on the frequency of applied electric field. (10+4) [K<sub>2</sub>]
25. Appraise the properties and applications of metallic glasses. (14) [K<sub>5</sub>]
26. Deduce an expression for Hall co-efficient. Describe an experimental method for evaluating the Hall co-efficient with a neat sketch. (10+4) [K<sub>4</sub>]

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